## NSN 5962-01-195-1230

Memory Microcircuit - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5962-01-195-1230 **Body Length:** Between 0.880 inches and 0.910 inches **Body Width:** Between 0.285 inches and 0.295 inches **Body Height:** Between 0.145 inches and 0.175 inches **Maximum Power Dissipation Rating:** 500.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and electrostatic sensitive and low power and high speed and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 16 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -4.0 volts power source and 11.0 volts power source **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 18 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: